### (19) World Intellectual Property Organization

International Bureau





## (43) International Publication Date 30 June 2005 (30.06.2005)

### **PCT**

# (10) International Publication Number WO 2005/059942 A3

(51) International Patent Classification7:

H01J 7/24

(21) International Application Number:

PCT/US2004/041525

(22) International Filing Date: 9 December 2004 (09.12.2004)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

60/529,343

12 December 2003 (12.12.2003) US

- (71) Applicant (for all designated States except US): SEME-QUIP, INC. [US/US]; 34 Sullivan Road, Unit 21, Billerica, MA 01862 (US).
- (72) Inventors; and
- (75) Inventors/Applicants (for US only): HORSKY, Thomas, N. [US/US]; 816 Depot Road, Boxborough, MA 01719 (US). MILGATE, Robert, W., III [—/US]; 2 Heath Heights, Gloucester, MA 01930 (US). SACCO, George, P., Jr. [—/US]; 51 Parsonage Lane, Topsfield, MA 01983 (US). JACOBSON, Dale, Conrad [—/US]; 16 Flintlock Road, Salem, NH 03079 (US). KRULL, Wade, Allen [—/US]; 8 Smith Street, Marblehead, MA 01945 (US).
- (74) Agent: WILLIAMS, John, N.; Fish & Richardson P.C., 225 Franklin Street, Boston, MA 02110-2804 (US).

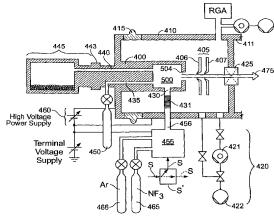
- (81) Designated States (unless otherwise indicated, for every kind of national protection available): AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW.
- (84) Designated States (unless otherwise indicated, for every kind of regional protection available): ARIPO (BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW), Eurasian (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European (AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR), OAPI (BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG).

#### Published:

- with international search report
- before the expiration of the time limit for amending the claims and to be republished in the event of receipt of amendments

[Continued on next page]

### (54) Title: METHOD AND APPARATUS FOR EXTENDING EQUIPMENT UPTIME IN ION IMPLANTATION



(57) Abstract: The service lifetime of an ion source (400) is enhanced or prolonged by the source having provisions for ire-situ etch cleaning of the ion source (400) and of an extraction electrode (405), using reactive halogen gases (F1, F2), and by having features that extend the service duration between cleanings. The latter include accurate vapor flow control, accurate focusing of the ion beam optics, and thermal control of the extraction electrode that prevents formation of deposits or prevents electrode destruction. An apparatus comprised of an ion source for generating dopant ions for semiconductor wafer processing is coupled to a remote plasma source which delivers F or Cl ions to the first ion source for the purpose of cleaning deposits in the first ion source and the extraction electrode. These methods and apparatus enable long equipment uptime when running condensable feed gases such as sublimated vapor sources, and are particularly applicable for use with so-called cold ion sources. Methods and apparatus are described which enable long equipment uptime when decaborane and octadecarborane are used as feed materials, as well as when vaporized elemental arsenic and phosphorus are used, and which serve to enhance beam stability during ion implantation.



2005/059942 43

### 

(88) Date of publication of the international search report:

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.